



MMBT5551Q

## Description

This bipolar junction transistor (BJT) is designed to meet the stringent requirements of automotive applications.

### **Features**

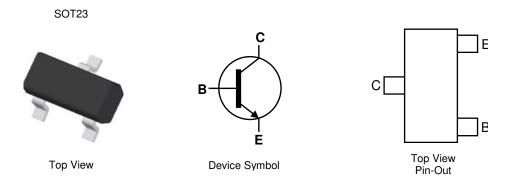
- BV<sub>CEO</sub> > 160V
- Ideal for Low Power Amplification and Switching
- Complementary PNP Type Available (MMBT5401)
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The MMBT5551Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

#### **160V NPN SMALL SIGNAL TRANSISTOR IN SOT23**

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.008 grams (Approximate)



#### Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
MMBT5551Q-7	K4N	7	8	3,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

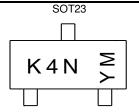
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

Notes:



K4N = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020)

M = Month (ex: 9 = September)

Date Code Key												
Year	2020	2021	1 20	)22	2023	2024	2025	2026	6 20	027	2028	2029
Code	Н	I		J	К	L	М	N		0	Р	R
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	180	V
Collector-Emitter Voltage	V <sub>CEO</sub>	160	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Continuous Collector Current (Note 5)	lc	600	mA

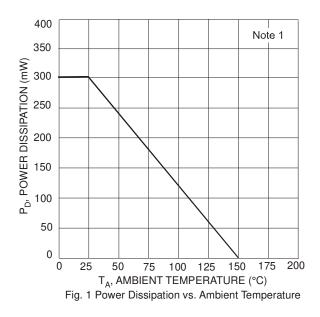
## Thermal Characteristics (@ T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient	R <sub>0JA</sub>	417	°C/W	
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	С°	

## ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air Notes: conditions whilst operating in a steady-state. 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





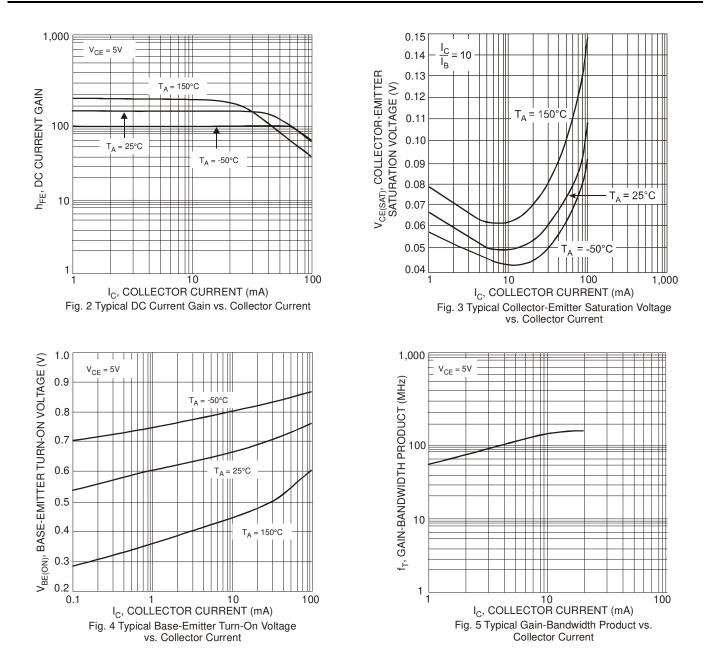
## **Electrical Characteristics** @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	180		V	$I_{\rm C} = 100 \mu A, I_{\rm E} = 0$	
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	160		V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	6.0		V	$I_{E} = 10 \mu A, I_{C} = 0$	
Collector Cutoff Current	I <sub>CBO</sub>		50	nA μA	$V_{CB} = 120V, I_E = 0$ $V_{CB} = 120V, I_E = 0, T_A = 100^{\circ}C$	
Emitter Cutoff Current	I <sub>EBO</sub>		50	nA	$V_{EB} = 4.0V, I_{C} = 0$	
ON CHARACTERISTICS (Note 7)						
DC Current Gain	h <sub>FE</sub>	80 80 30	 250 	_	$\begin{split} I_{C} &= 1.0mA,  V_{CE} = 5.0V \\ I_{C} &= 10mA,  V_{CE} = 5.0V \\ I_{C} &= 50mA,  V_{CE} = 5.0V \end{split}$	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_	0.15 0.20	V	$I_{C} = 10mA, I_{B} = 1.0mA$ $I_{C} = 50mA, I_{B} = 5.0mA$	
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	_	1.0	V	$I_{C} = 10mA, I_{B} = 1.0mA$ $I_{C} = 50mA, I_{B} = 5.0mA$	
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C <sub>obo</sub>	_	6.0	pF	$V_{CB} = 10V, f = 1.0MHz, I_E = 0$	
Small Signal Current Gain	h <sub>fe</sub>	50	250	—	$V_{CE} = 10V, I_C = 1.0mA,$ f = 1.0kHz	
Current Gain-Bandwidth Product	ft	100	300	MHz	$\label{eq:VCE} \begin{array}{l} V_{CE} = 10V, \ I_{C} = 10mA, \\ f = 100MHz \end{array}$	
Noise Figure	nf		8.0	dB	$\label{eq:VCE} \begin{split} V_{CE} &= 5.0V, \ I_C = 200 \mu A, \\ R_S &= 1.0 k \Omega, \ f = 1.0 k Hz \end{split}$	

Notes: 7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



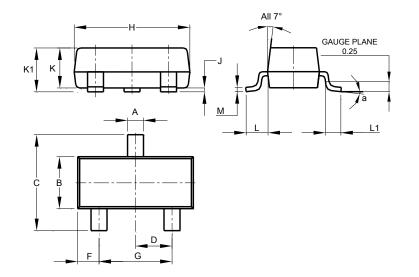
## Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)





## **Package Outline Dimensions**

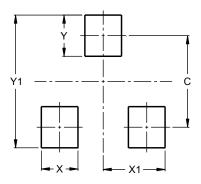
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Η	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
Μ	0.085	0.150	0.110					
а	0°	8°						
All	All Dimensions in mm							

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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